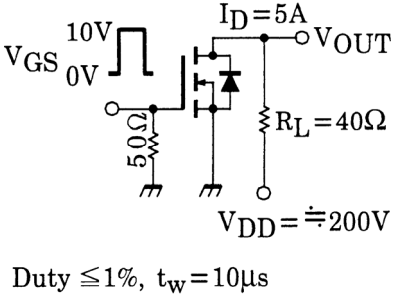




## Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		$I_{GSS}$	$V_{GS} = \pm 25 \text{ V}$ , $V_{DS} = 0 \text{ V}$	—	—	$\pm 10$	$\mu\text{A}$
Gate-source breakdown voltage		$V_{(BR)GSS}$	$I_G = \pm 10 \mu\text{A}$ , $V_{DS} = 0 \text{ V}$	$\pm 30$	—	—	V
Drain cut-off current		$I_{DSS}$	$V_{DS} = 450 \text{ V}$ , $V_{GS} = 0 \text{ V}$	—	—	100	$\mu\text{A}$
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 10 \text{ mA}$ , $V_{GS} = 0 \text{ V}$	450	—	—	V
Gate threshold voltage		$V_{th}$	$V_{DS} = 10 \text{ V}$ , $I_D = 1 \text{ mA}$	2.4	—	3.4	V
Drain-source ON resistance		$R_{DS(ON)}$	$V_{GS} = 10 \text{ V}$ , $I_D = 5 \text{ A}$	—	0.48	0.65	$\Omega$
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 10 \text{ V}$ , $I_D = 5 \text{ A}$	3.5	7.5	—	S
Input capacitance		$C_{iss}$	$V_{DS} = 10 \text{ V}$ , $V_{GS} = 0 \text{ V}$ , $f = 1 \text{ MHz}$	—	1400	—	pF
Reverse transfer capacitance		$C_{rss}$		—	240	—	
Output capacitance		$C_{oss}$		—	590	—	
Switching time	Rise time	$t_r$	 <p><math>I_D = 5 \text{ A}</math> <math>V_{GS} = 10 \text{ V}</math>, <math>0 \text{ V}</math> <math>50 \Omega</math> <math>R_L = 40 \Omega</math> <math>V_{DD} = 200 \text{ V}</math> Duty <math>\leq 1\%</math>, <math>t_w = 10 \mu\text{s}</math></p>	—	35	—	ns
	Turn-on time	$t_{on}$		—	50	—	
	Fall time	$t_f$		—	80	—	
	Turn-off time	$t_{off}$		—	260	—	
Total gate charge (Gate-source plus gate-drain)		$Q_g$	$V_{DD} \approx 400 \text{ V}$ , $V_{GS} = 10 \text{ V}$ , $I_D = 10 \text{ A}$	—	35	—	nC
Gate-source charge		$Q_{gs}$		—	19	—	
Gate-drain ("miller") charge		$Q_{gd}$		—	16	—	

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	$I_{DR}$	—	—	—	10	A
Pulse drain reverse current (Note 1)	$I_{DRP}$	—	—	—	40	A
Forward voltage (diode)	$V_{DSF}$	$I_{DR} = 10 \text{ A}$ , $V_{GS} = 0 \text{ V}$	—	—	-1.7	V
Reverse recovery time	$t_{rr}$	$I_{DR} = 10 \text{ A}$ , $V_{GS} = 0 \text{ V}$	—	1400	—	ns
Reverse recovery charge	$Q_{rr}$	$dI_{DR} / dt = 100 \text{ A} / \mu\text{s}$	—	14	—	$\mu\text{C}$

## Marking

